



# **N-Channel Power MOSFET**

600V, 18A, 0.19Ω

#### **FEATURES**

- Super-Junction technology
- High performance, small R<sub>DS(ON)</sub>\*Q<sub>g</sub> figure of merit (FOM)
- High ruggedness performance
- 100% UIS & R<sub>g</sub> tested
- High commutation performance
- Pb-free plating
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

KEY PERFORMANCE PARAMETERS			
PARAMETER VALUE UNIT			
V <sub>DS</sub>	600	V	
R <sub>DS(on)</sub> (max)	0.19	Ω	
$Q_g$	31	nC	



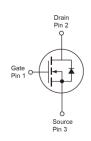




#### **APPLICATIONS**

- Power Supply
- AC/DC LED Lighting





Note: MSL 3 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)				
PARAMETER		SYMBOL	Limit	UNIT
Drain-Source Voltage		V <sub>DS</sub>	600	V
Gate-Source Voltage		$V_{GS}$	±30	V
Continuous Drain Current (Note 1)	T <sub>C</sub> = 25°C		18	Α
	$T_C = 100$ °C	I <sub>D</sub>	10.8	Α
Pulsed Drain Current (Note 2)		I <sub>DM</sub>	54	Α
Total Power Dissipation @ T <sub>C</sub> = 25°C		P <sub>DTOT</sub>	150.6	W
Single Pulsed Avalanche Energy (Note 3)		E <sub>AS</sub>	212.9	mJ
Single Pulsed Avalanche Current (Note 3)		I <sub>AS</sub>	2.6	Α
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	- 55 to +150	°C

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	Limit	UNIT	
Junction to Case Thermal Resistance	R <sub>eJC</sub>	0.83	°C/W	
Junction to Ambient Thermal Resistance	R <sub>OJA</sub>	62	°C/W	

**Thermal Performance Note:**  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins.  $R_{\theta JA}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.  $R_{\theta JA}$  shown below for single device operation on FR-4 PCB with minimum recommended footprint in still air.

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PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static	<u>,                                      </u>					•
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV <sub>DSS</sub>	600			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	$V_{GS(TH)}$	2.0	3.0	4.0	V
Gate Body Leakage	$V_{GS} = \pm 30V, V_{DS} = 0V$	I <sub>GSS</sub>			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = 600V, V_{GS} = 0V$	I <sub>DSS</sub>			1	μA
Drain-Source On-State Resistance (Note 4)	V <sub>GS</sub> = 10V, I <sub>D</sub> = 6A	R <sub>DS(on)</sub>		0.17	0.19	Ω
Dynamic (Note 5)				<u>I</u>		
Total Gate Charge	$V_{DS} = 380V, I_D = 18A,$ $V_{GS} = 10V$	Qg		31		
Gate-Source Charge		Q <sub>gs</sub>		8		nC
Gate-Drain Charge		$Q_{gd}$		12.6		
Input Capacitance	$V_{DS} = 100V, V_{GS} = 0V,$ f = 1.0MHz	C <sub>iss</sub>		1273		_
Output Capacitance		C <sub>oss</sub>		92		pF
Gate Resistance		$R_g$		3.1	6.2	Ω
Switching (Note 6)	<u>,                                      </u>					•
Turn-On Delay Time	$V_{DD} = 380V,$ $R_{GEN} = 25\Omega,$ $I_{D} = 18A, V_{GS} = 10V,$	t <sub>d(on)</sub>		36		
Turn-On Rise Time		t <sub>r</sub>		21		
Turn-Off Delay Time		t <sub>d(off)</sub>		95		ns
Turn-Off Fall Time	$I_{D} = IOA, V_{GS} = IOV,$	t <sub>f</sub>		21		1
Source-Drain Diode						•
Forward On Voltage (Note 4)	I <sub>S</sub> = 18A, V <sub>GS</sub> = 0V	V <sub>SD</sub>			1.4	V
Reverse Recovery Time	V <sub>R</sub> =100V, I <sub>S</sub> = 18A	t <sub>rr</sub>		359.4		ns
Reverse Recovery Charge	$dI_F/dt = 100A/\mu s$	Q <sub>rr</sub>		4.54		μC

#### Notes:

- 1. Current limited by package.
- 2. Pulse width limited by the maximum junction temperature.
- 3. L = 63mH,  $I_{AS} = 2.6A$ ,  $V_{DD} = 50V$ ,  $R_G = 25\Omega$ , Starting  $T_J = 25^{\circ}C$
- 4. Pulse test: PW ≤ 300µs, duty cycle ≤ 2%.
- 5. For DESIGN AID ONLY, not subject to production testing.
- 6. Switching time is essentially independent of operating temperature.

#### **ORDERING INFORMATION**

PART NO.	PACKAGE	PACKING
TSM60NB190CM2 RNG	TO-263 (D <sup>2</sup> PAK )	800pcs / 13" Reel

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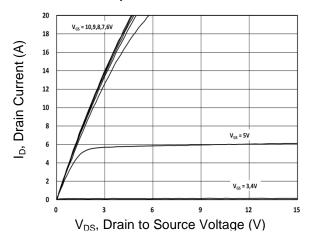
Version: A1608



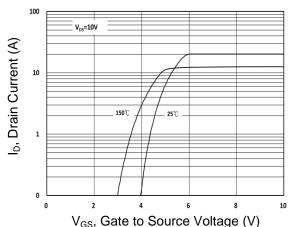
#### **CHARACTERISTICS CURVES**

 $(T_C = 25^{\circ}C \text{ unless otherwise noted})$ 

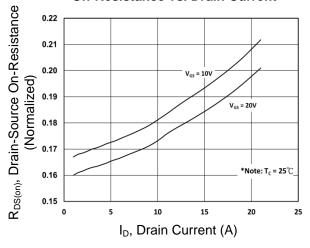
#### **Output Characteristics**



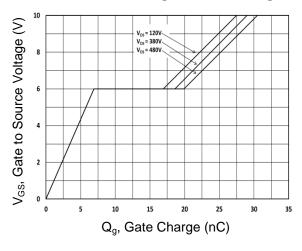
# Transfer Characteristics



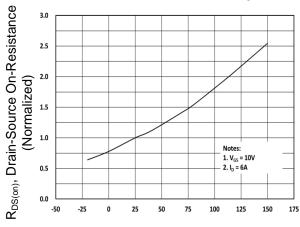
#### On-Resistance vs. Drain Current



#### Gate-Source Voltage vs. Gate Charge

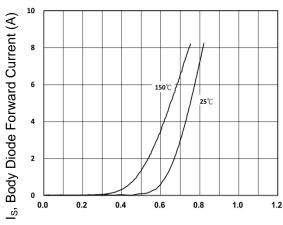


# On-Resistance vs. Junction Temperature



T<sub>J</sub>, Junction Temperature (°C)

# Source-Drain Diode Forward Current vs. Voltage



V<sub>SD</sub>, Body Diode Forward Voltage (V)

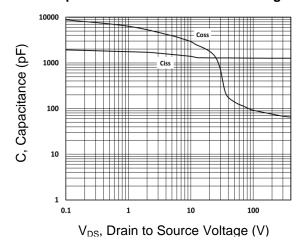
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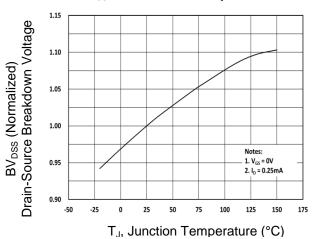
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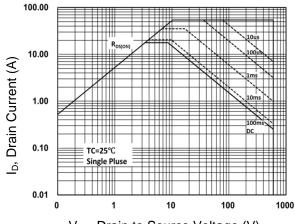
# Capacitance vs. Drain-Source Voltage

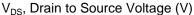


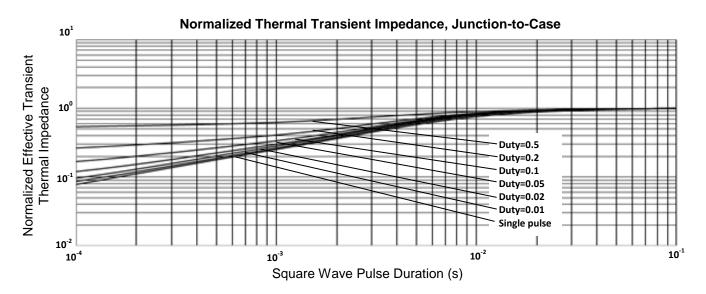
# BV<sub>DSS</sub> vs. Junction Temperature



# **Maximum Safe Operating Area**

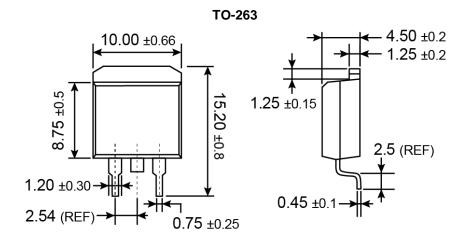




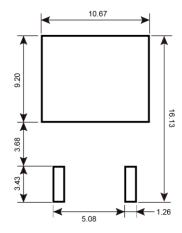




# PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)



# SUGGESTED PAD LAYOUT (Unit: Millimeters)



# **MARKING DIAGRAM**



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= Halogen Free

= Year Code

**WW** = Week Code (01~52)

= Factory Code





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